LOW NOISE 150mA LDO REGULATOR

NO. EA-057-0204

R1111N SERIES

OUTLINE

The R1111N Series are CMOS-based voltage regulator ICs with high output voltage accuracy, extremely low supply current, low ON-resistance, and high Ripple Rejection. Each of these voltage regulator ICs consists of a voltage reference unit, an error amplifier, resistors, a current limit circuit, and a chip enable circuit.

These ICs perform with low dropout voltage and a chip enable function. The line transient response and load transient response of the R1111N Series are excellent, thus these ICs are very suitable for the power supply for hand-held communication equipment.

The output voltage of these ICs is fixed with high accuracy. Since the package for these ICs is SOT-23-5 (Mini-mold) package , high density mounting of the ICs on boards is possible.

FEATURES

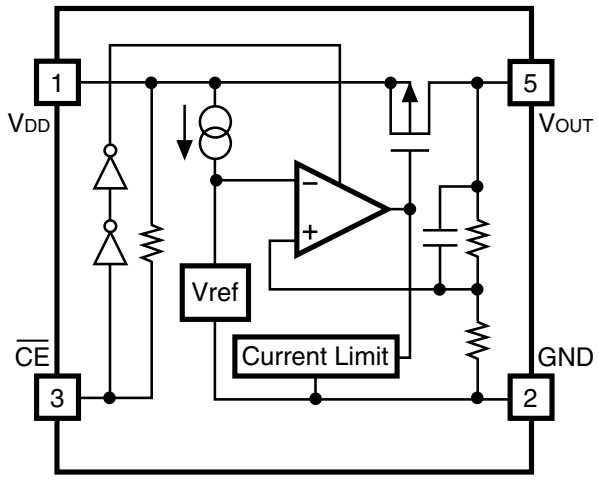
- Ultra-Low Supply Current ..... Typ. 35μA
- Standby Mode ..... Typ. 0.1μA
- Low Dropout Voltage ..... Typ. 0.2V(I_{OUT}=100mA)
- High Ripple Rejection ..... Typ. 70dB(f=1kHz)
- Low Temperature-Drift Coefficient of Output Voltage..... Typ. ±100ppm/°C
- Excellent Line Regulation..... Typ. 0.05%/V
- High Output Voltage Accuracy ..... ±2.0%
- Excellent Line Transient Response and Load Transient Response
- Small Package ..... SOT-23-5(Mini-mold)
- Output Voltage..... Stepwise setting with a step of 0.1V in the range of 1.5V to 5.0V is possible
- Built-in chip enable circuit (2 types; A: active “L”, B: active “H”)
- Pin out..... Similar to the LP2980

APPLICATIONS

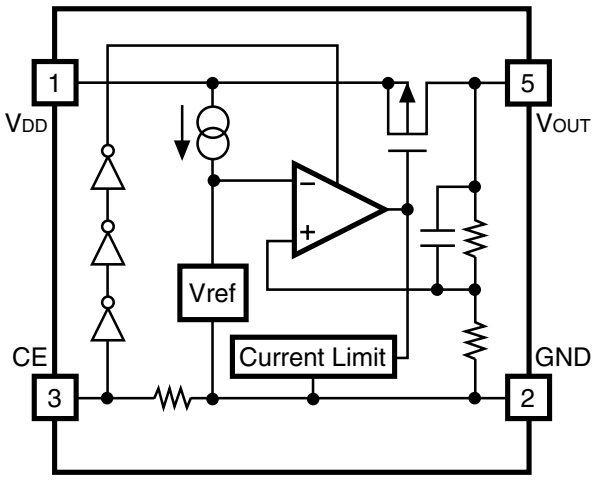
- Power source for cellular phones such as GSM,CDMA and various kind of PCSs.
- Power source for electrical appliances such as cameras, VCRs and camcorders.
- Power source for battery-powered equipment.

BLOCK DIAGRAM

R1111Nxx1A



R1111Nxx1B



SELECTION GUIDE

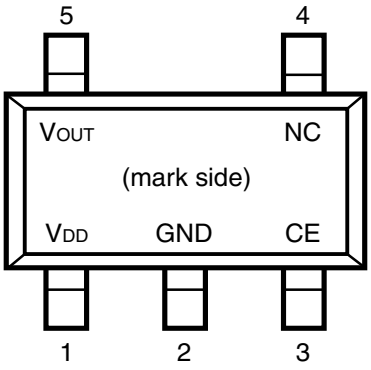
The output voltage, the active type, the packing type, and the taping type for the ICs can be selected at the user's request. The selection can be made by designating the part number as shown below :

R1111xxx1x-xx ←Part Number
↑↑ ↑ ↑
a b c d

Code	Contents
a	Designation of Package Type : N:SOT-23-5 (Mini-mold)
b	Setting Output Voltage (V_{OUT}) : Stepwise setting with a step of 0.1V in the range of 1.5V to 5.0V is possible.
c	Designation of Active Type : A :"L" active type B :"H" active type
d	Designation of Taping Type : Ex. TR, TL (refer to Taping Specifications ;TR type is the standard direction.)

PIN CONFIGURATION

SOT-23-5



PIN DESCRIPTION

Pin No.	Symbol	Description
1	V_{DD}	Input Pin
2	GND	Ground Pin
3	$\overline{CE}$ or CE	Chip Enable Pin
4	NC	No Connection
5	V_{OUT}	Output pin

ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Rating	Unit
Input Voltage	V_{IN}	9	V
Input Voltage($\overline{CE}$ or CE Pin)	V_{CE}	-0.3 ~ V_{IN}+0.3	V
Output Voltage	V_{OUT}	-0.3 ~ V_{IN}+0.3	V
Output Current	I_{OUT}	200	mA
Power Dissipation	P_D	250	mW
Operating Temperature Range	Topt	-40 ~ 85	°C
Storage Temperature Range	Tstg	-55 ~ 125	°C

ELECTRICAL CHARACTERISTICS

- **R1111Nxx1A**

Topt=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V_{OUT}	Output Voltage	V_{IN} = Set V_{OUT}+1V 1mA ≤ I_{OUT} ≤ 30mA	V_{OUT} ×0.98		V_{OUT} ×1.02	V
I_{OUT}	Output Current	Refer to the ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE				
$\Delta V_{OUT}/\Delta I_{OUT}$	Load Regulation	V_{IN} = Set V_{OUT}+1V 1mA ≤ I_{OUT} ≤ 80mA		12	40	mV
V_{DIF}	Dropout Voltage	Refer to the ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE				
I_{SS}	Supply Current	V_{IN} = Set V_{OUT}+1V		35	70	μA
Istandby	Supply Current (Standby)	V_{IN} = V_{CE} = Set V_{OUT}+1V		0.1	1.0	μA
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	Set V_{OUT}+0.5V ≤ V_{IN} ≤ 8V I_{OUT} = 30mA		0.05	0.20	%/V
RR	Ripple Rejection	f = 1kHz, Ripple 0.5Vp-p V_{IN} = Set V_{OUT}+1V		70		dB
V_{IN}	Input Voltage		2		8	V
$\Delta V_{OUT}/\Delta T$	Output Voltage Temperature Coefficient	I_{OUT} = 30mA -40°C ≤ Topt ≤ 85°C		±100		ppm /°C
Ilim	Short Current Limit	V_{OUT} = 0V		50		mA
R_{PU}	$\overline{CE}$ Pull-up Resistance		2.5	5.0	10.0	MΩ
V_{CEH}	$\overline{CE}$ Input Voltage "H"		1.5		V_{IN}	V
V_{CEL}	$\overline{CE}$ Input Voltage "L"		0.00		0.25	V
en	Output Noise	BW = 10Hz ~ 100kHz		30		μVrms

• **R1111Nxx1B**

Topt=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V_{OUT}	Output Voltage	V_{IN} = Set V_{OUT}+1V 1mA ≤ I_{OUT} ≤ 30mA	V_{OUT} ×0.98		V_{OUT} ×1.02	V
I_{OUT}	Output Current	Refer to the ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE				
$\Delta V_{OUT}/\Delta I_{OUT}$	Load Regulation	V_{IN} = Set V_{OUT}+1V 1mA ≤ I_{OUT} ≤ 80mA		12	40	mV
V_{DIF}	Dropout Voltage	Refer to the ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE				
I_{SS}	Supply Current	V_{IN} = Set V_{OUT}+1V		35	70	µA
Istandby	Supply Current (Standby)	V_{IN} = Set V_{OUT}+1V V_{CE}=GND		0.1	1.0	µA
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	Set V_{OUT}+0.5V ≤ V_{IN} ≤ 8V I_{OUT} = 30mA		0.05	0.20	%/V
RR	Ripple Rejection	f = 1KHz, Ripple 0.5Vp-p V_{IN} = Set V_{OUT}+1V		70		dB
V_{IN}	Input Voltage		2		8	V
$\Delta V_{OUT}/\Delta T$	Output Voltage Temperature Coefficient	I_{OUT} = 30mA -40°C ≤ Topt ≤ 85°C		±100		ppm /°C
Ilim	Short Current Limit	V_{OUT} = 0V		50		mA
R_{PD}	CE Pull-down Resistance		2.5	5.0	10.0	MΩ
V_{CEH}	CE Input Voltage "H"		1.5		V_{IN}	V
V_{CEL}	CE Input Voltage "L"		0.00		0.25	V
en	Output Noise	BW = 10Hz ~ 100kHz		30		µVrms

- **ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE**

Topt = 25°C

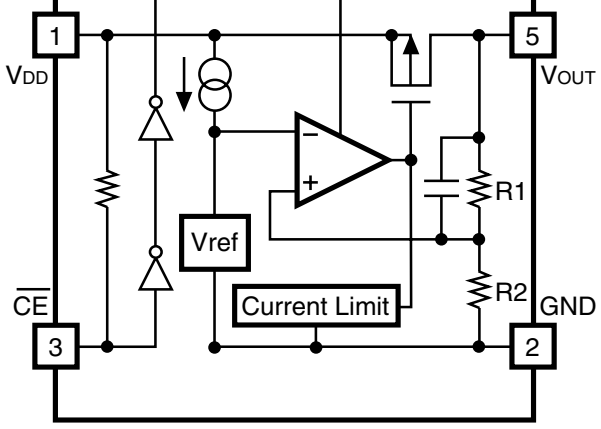
Output Voltage	Output Current	
	I_{OUT} (mA)	
	Condition	Min.
$1.5 \le V_{OUT} \le 1.7$	$V_{IN} - V_{OUT} = 1.0V$	100
$1.8 \le V_{OUT} \le 5.0$		150

Topt = 25°C

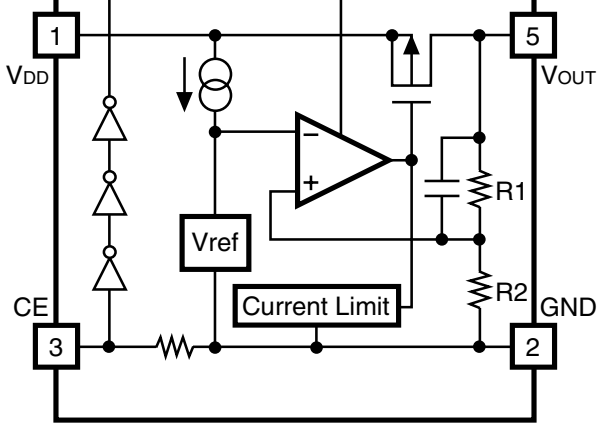
Output Voltage V_{OUT} (V)	Dropout Voltage			
	V_{DIF} (V)			
	Condition	Min.	Typ.	Max.
1.5	I_{OUT} = 100mA	0.50		
1.6		0.40		
1.7		0.30		
$1.8 \le V_{OUT} \le 1.9$			0.60	1.40
$2.0 \le V_{OUT} \le 2.4$			0.35	0.70
$2.5 \le V_{OUT} \le 2.7$			0.24	0.35
$2.8 \le V_{OUT} \le 3.3$			0.20	0.30
$3.4 \le V_{OUT} \le 5.0$			0.17	0.26

OPERATION

R1111Nxx1A



R1111Nxx1B



In these ICs, fluctuation of the output voltage, V_{OUT} is detected by feed-back registers R1, R2, and the result is compared with a reference voltage by the error amplifier, so that a constant voltage is output. A current limit circuit for protection at short mode and a chip enable circuit, are included.

TEST CIRCUITS

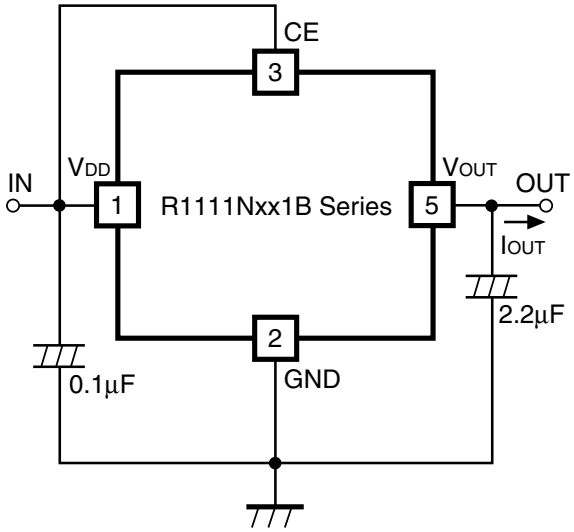


Fig.1 Standard test Circuit

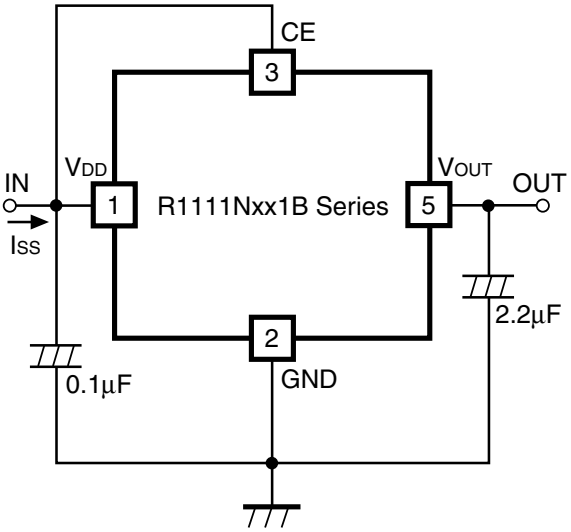


Fig.2 Supply Current Test Circuit

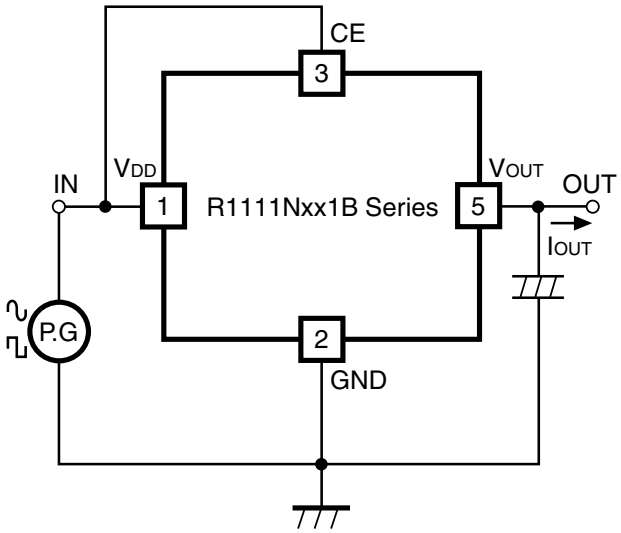


Fig.3 Ripple Rejection, Line Transient Response Test Circuit

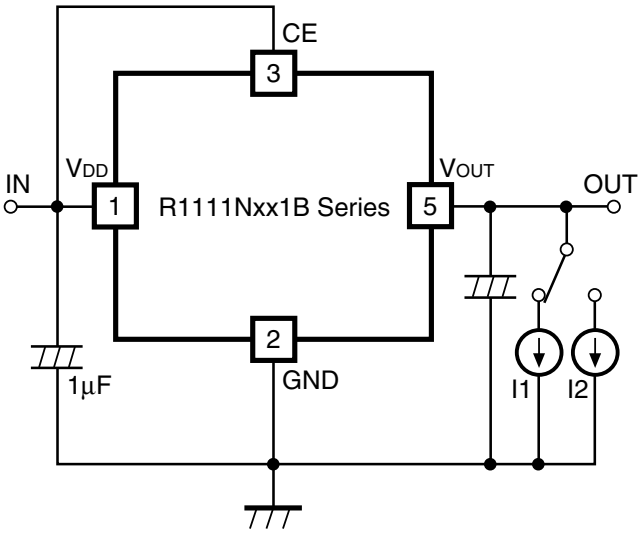
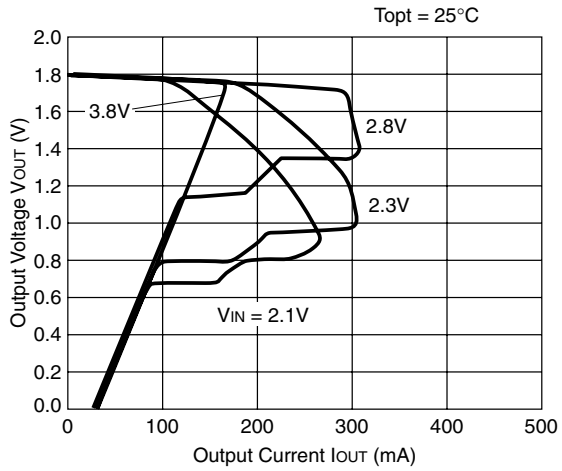


Fig.4 Load Transient Response Test Circuit

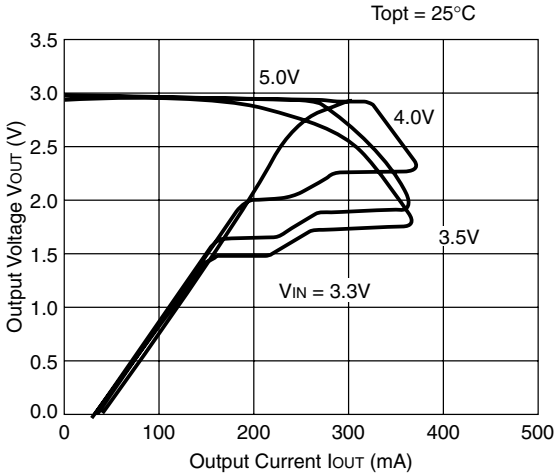
TYPICAL CHARACTERISTICS

1) Output Voltage vs. Output Current

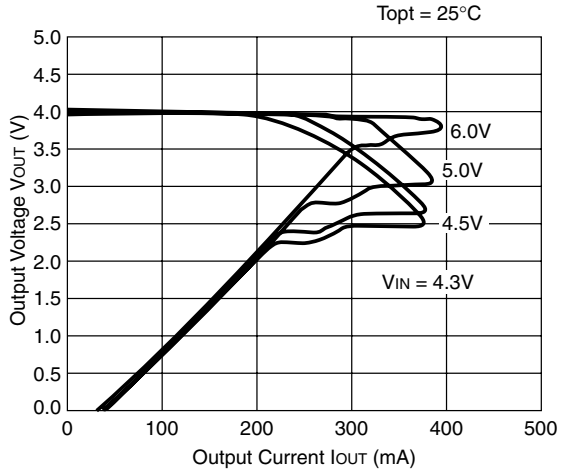
R1111N181B



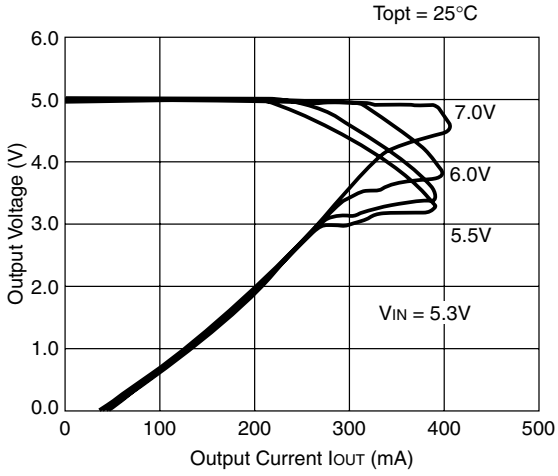
R1111N301B



R1111N401B

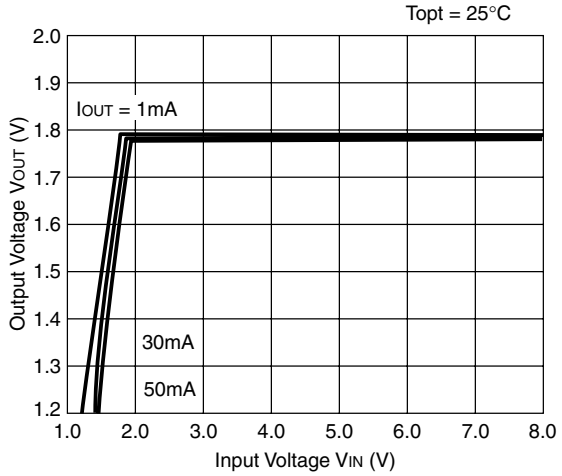


R1111N501B

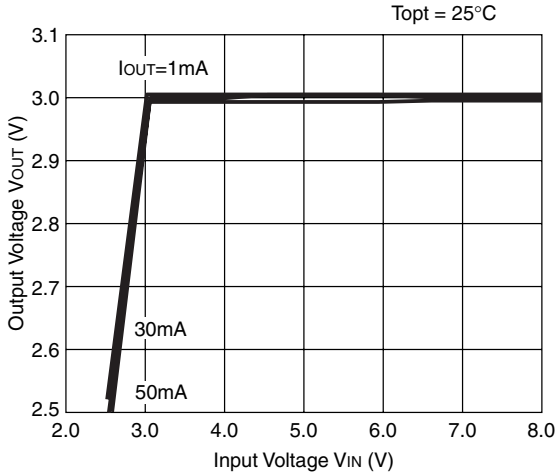


2) Output Voltage vs. Input Voltage

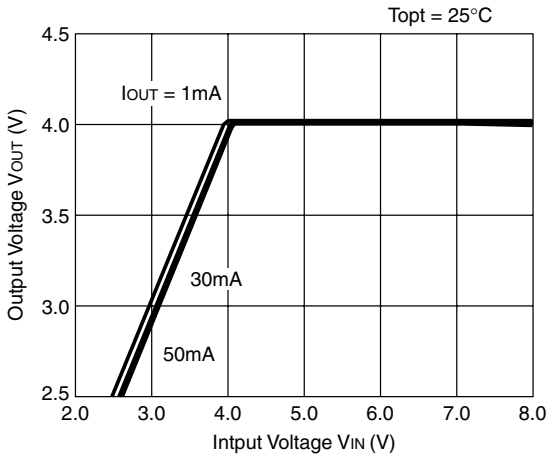
R1111N181B



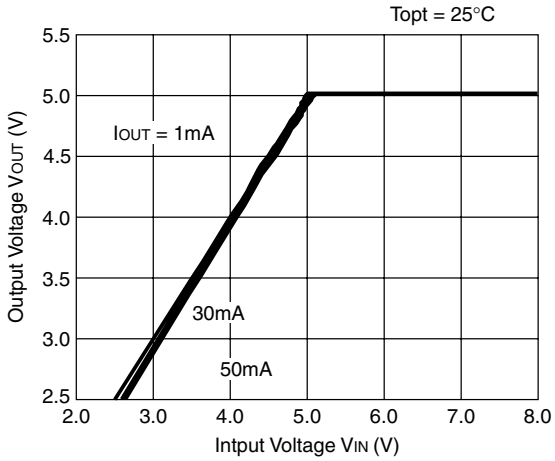
R1111N301B



R1111N401B

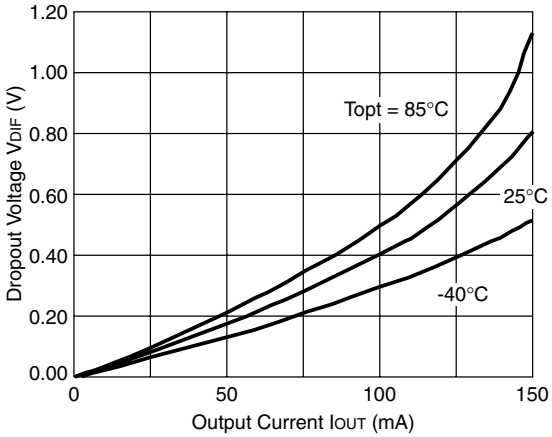


R1111N501B

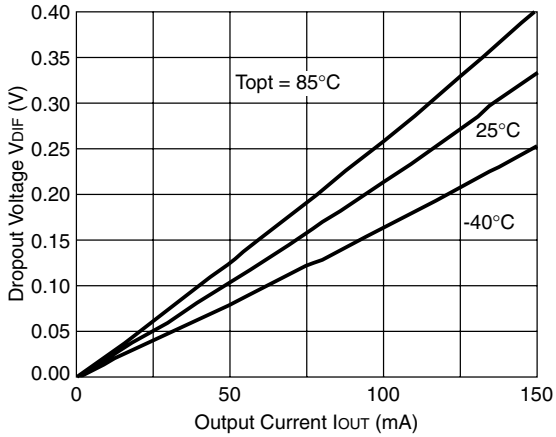


3) Dropout Voltage vs. Output Current

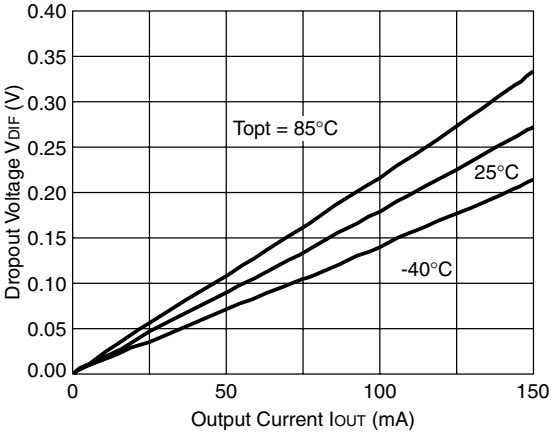
R1111N181B



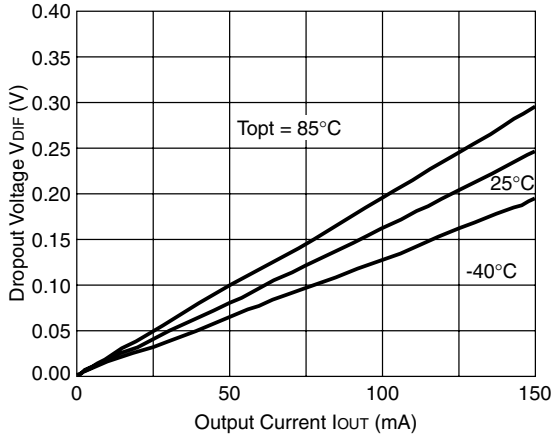
R1111N301B



R1111N401B

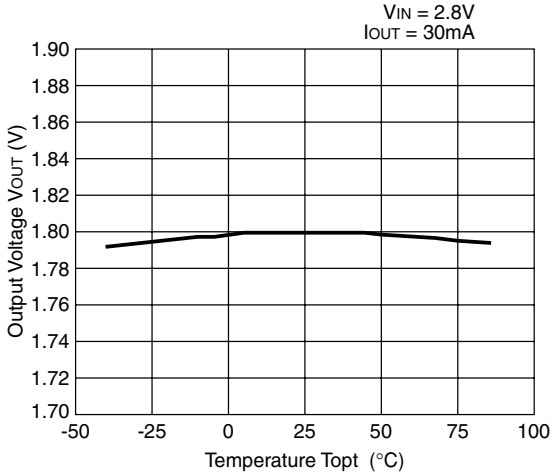


R1111N501B

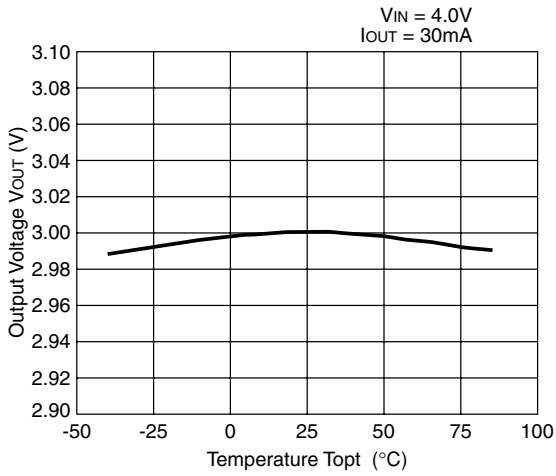


4) Output Voltage vs. Temperature

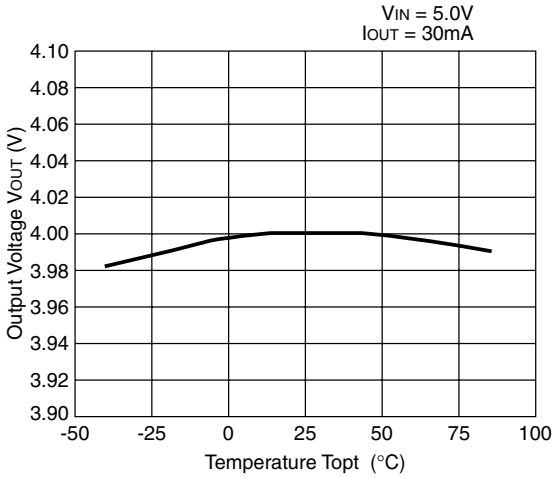
R1111N181B



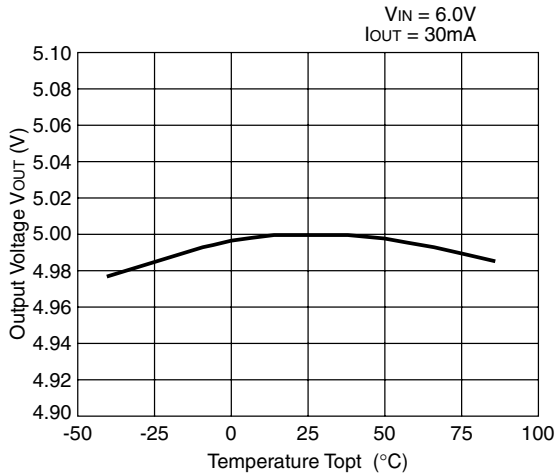
R1111N301B



R1111N401B

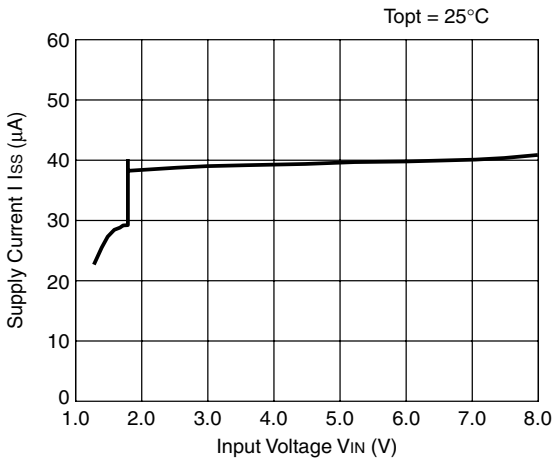


R1111N501B

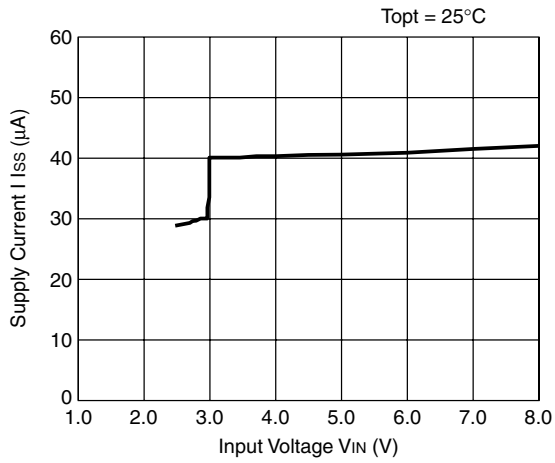


5) Supply Current vs. Input Voltage

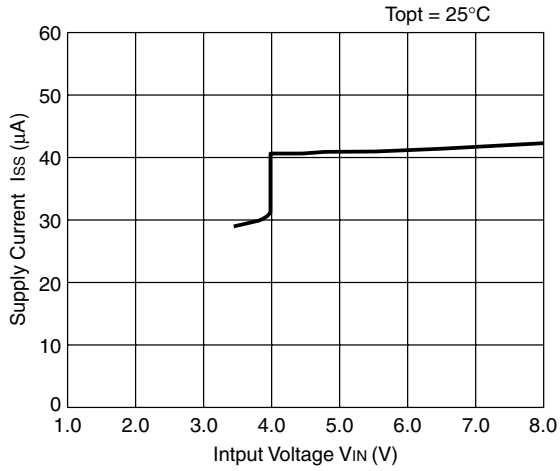
R1111N181B



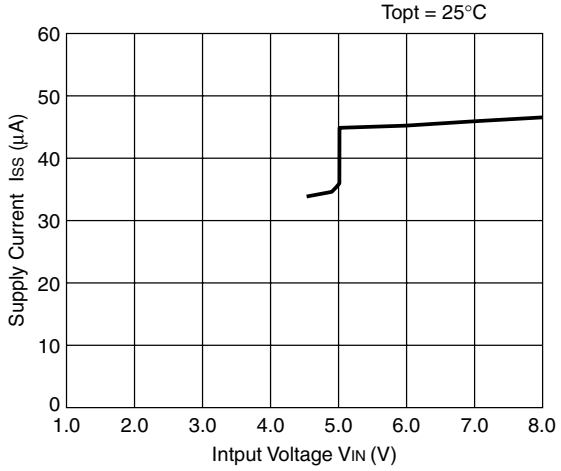
R1111N301B



R1111N401B

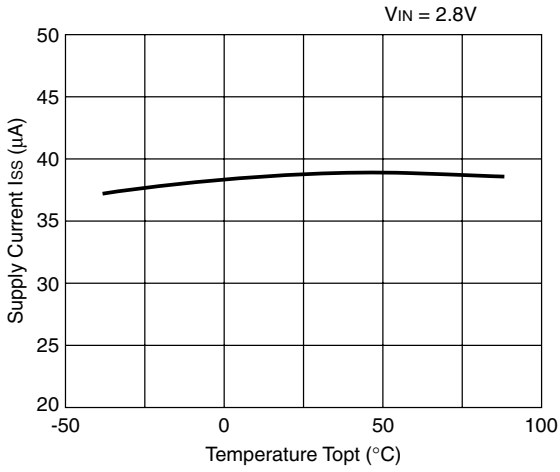


R1111N501B

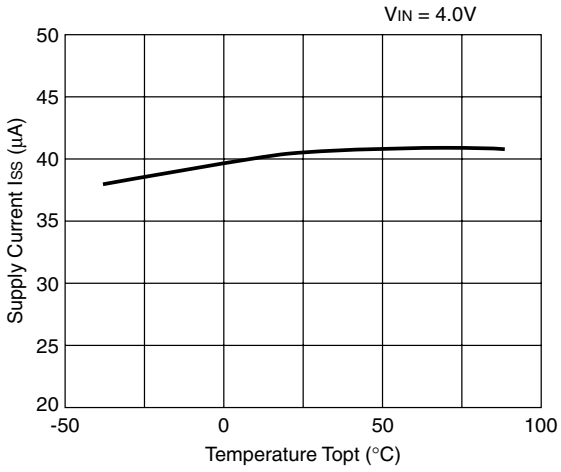


6) Supply Current vs. Temperature

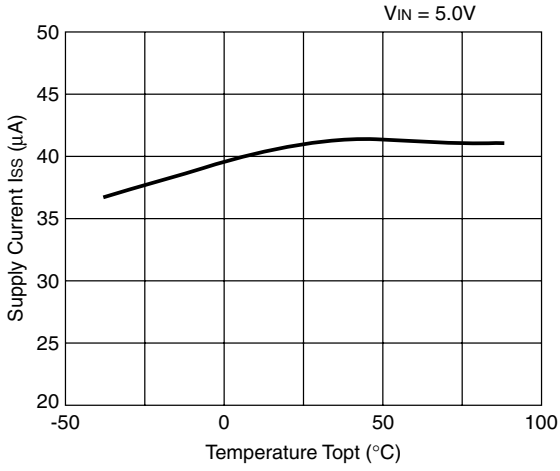
R1111N181B



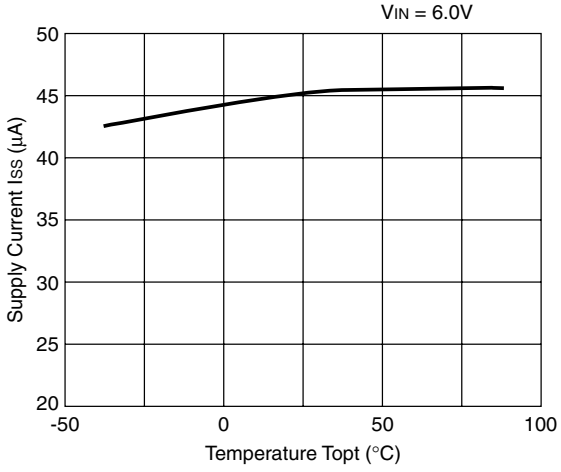
R1111N301B



R1111N401B

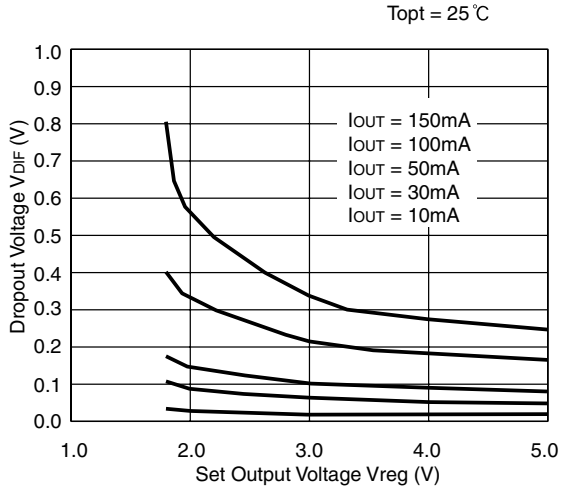


R1111N501B



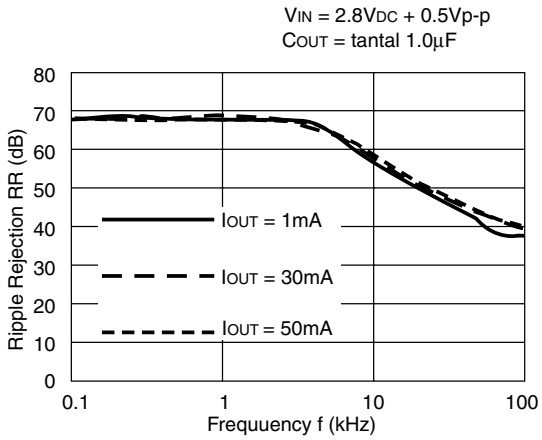
7) Dropout Voltage vs. Set Output Voltage

R1111Nxx1B

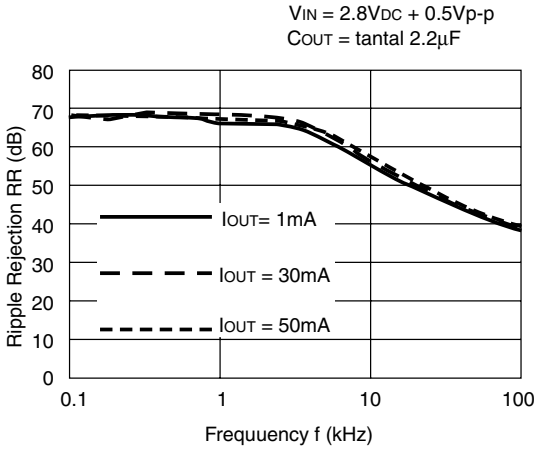


8) Ripple Rejection vs. Frequency

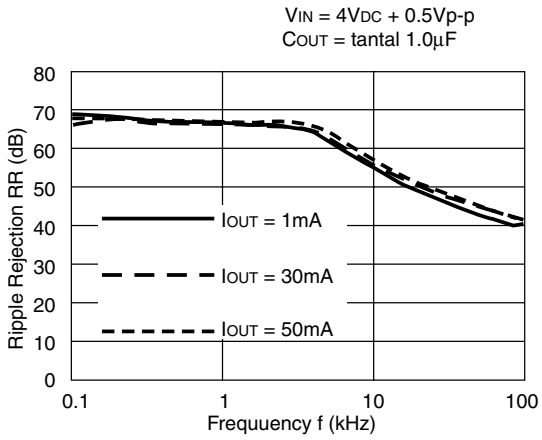
R1111N181B



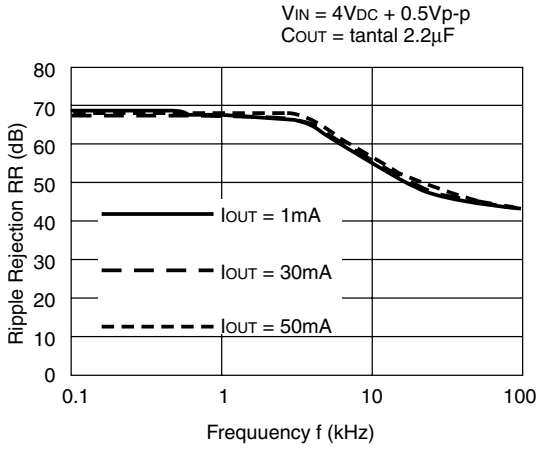
R1111N181B



R1121N301B

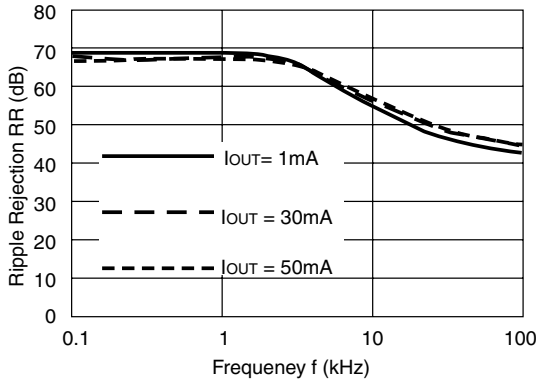


R1121N301B



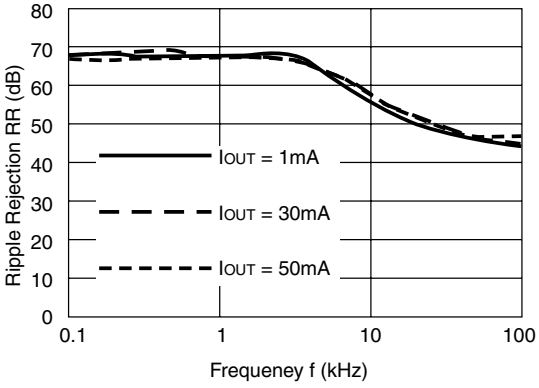
R1111N401B

V_{IN} = 5.0V_{DC} + 0.5Vp-p
C_{OUT} = tantal 1.0µF



R1111N401B

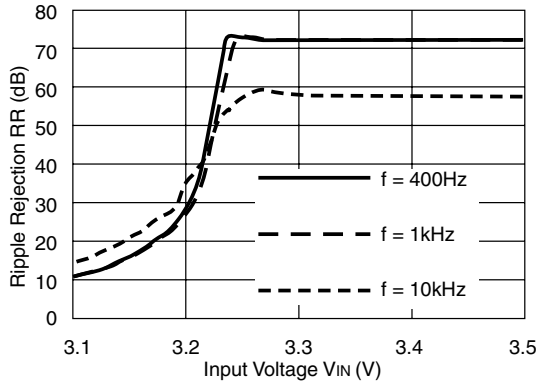
V_{IN} = 5.0V_{DC} + 0.5Vp-p
C_{OUT} = tantal 2.2µF



9) Ripple Rejection vs. Input Voltage (DC bias)

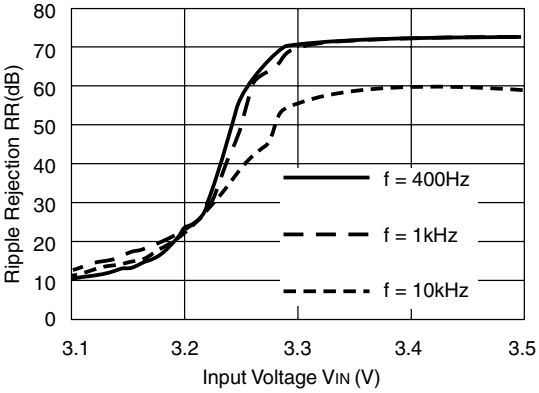
R1111N301B

I_{OUT} = 1mA
C_{OUT} = 2.2µF



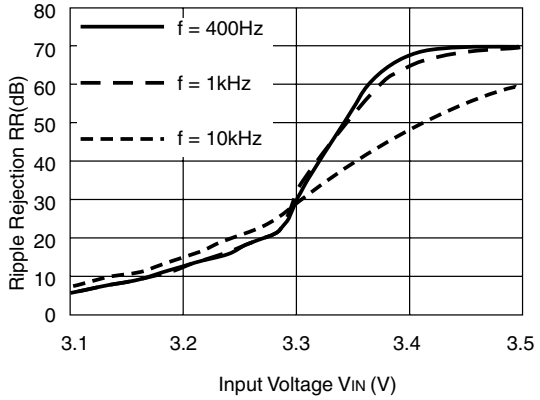
R1111N301B

I_{OUT} = 10mA
C_{OUT} = 2.2µF



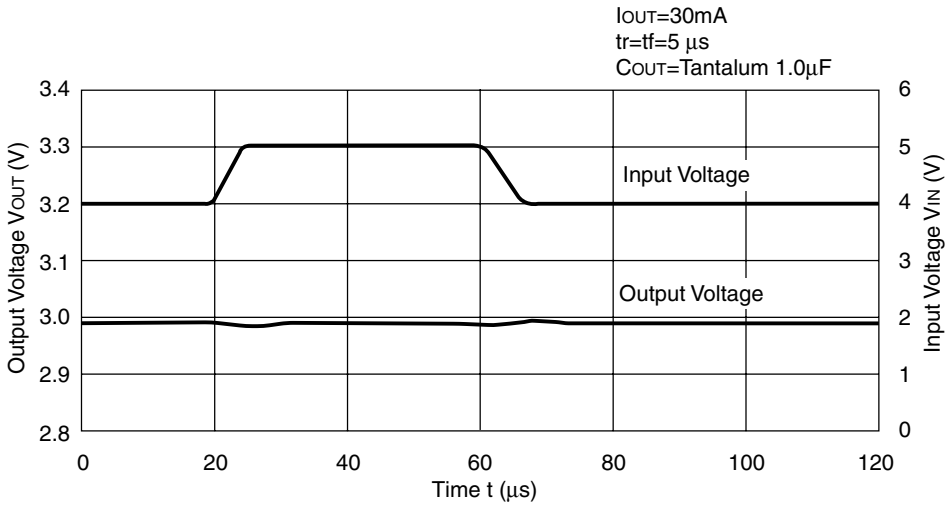
R1111N301B

I_{OUT} = 50mA
C_{OUT} = 2.2µF

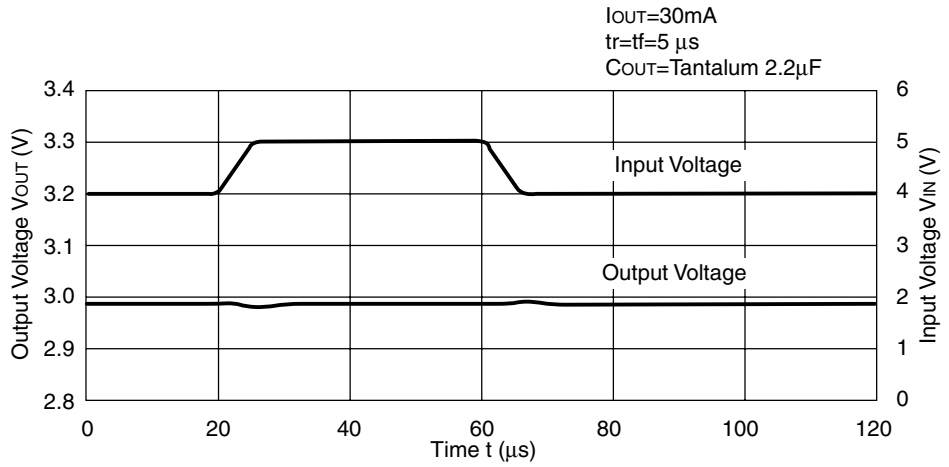


10) Line Transient Response

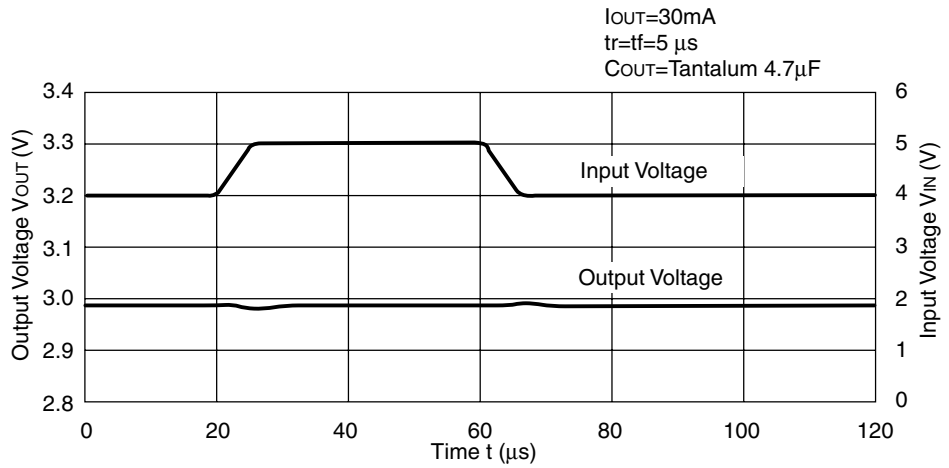
R1111N301B



R1111N301B



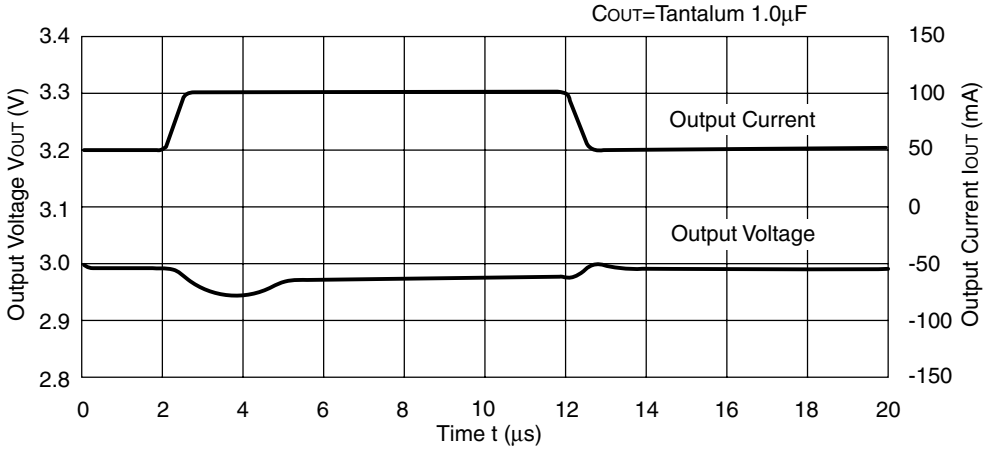
R1111N301B



11) Load Transient Response

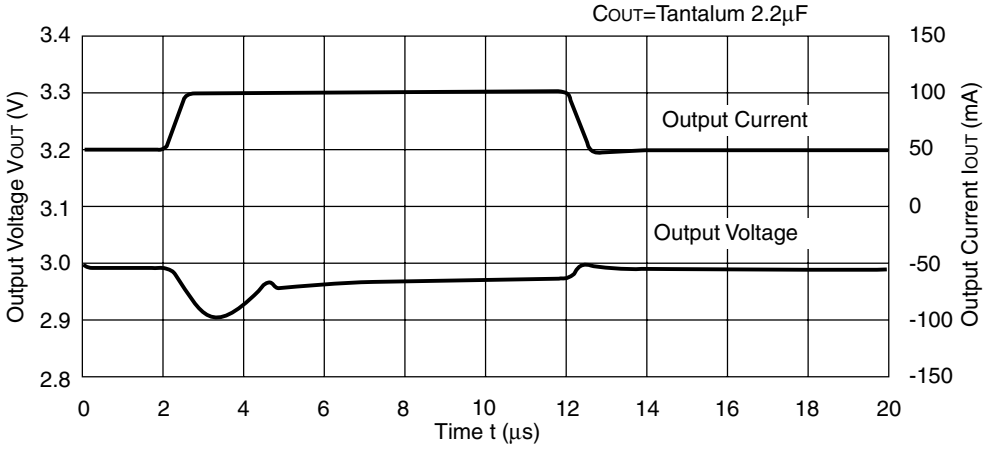
R1111N301B

V_{IN}=4V
C_{IN}=Tantalum 1μF
C_{OUT}=Tantalum 1.0μF



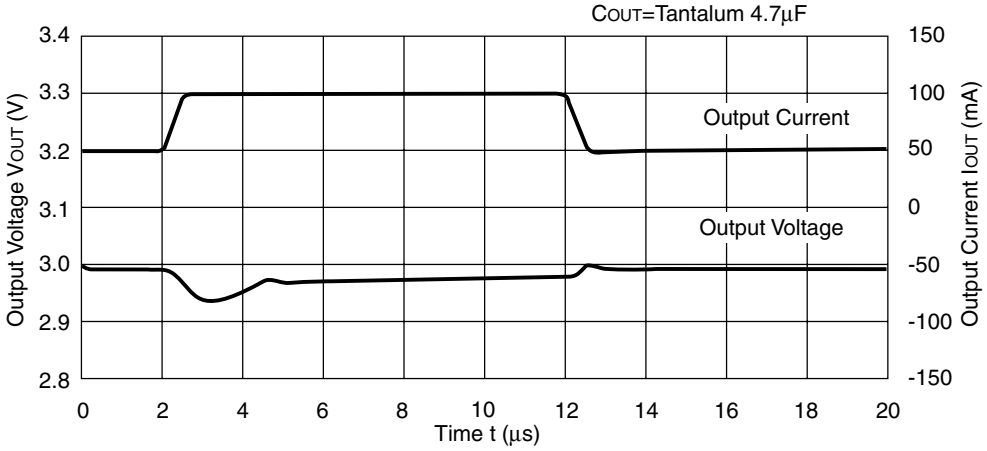
R1111N301B

V_{IN}=4V
C_{IN}=Tantalum 1μF
C_{OUT}=Tantalum 2.2μF



R1111N301B

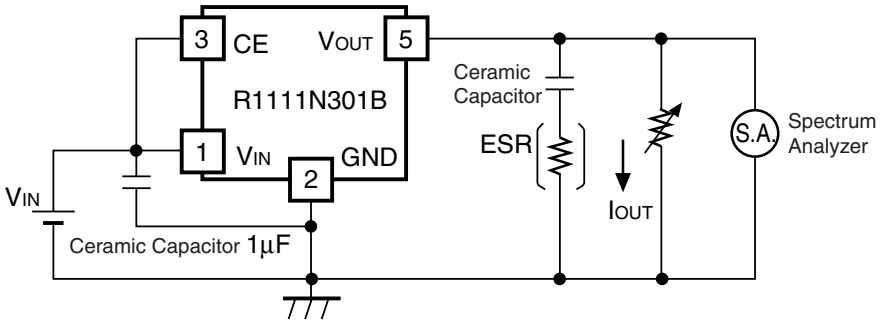
V_{IN}=4V
C_{IN}=Tantalum 1μF
C_{OUT}=Tantalum 4.7μF



TECHNICAL NOTES

When using these ICs, consider the following points:

In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, be sure to use a capacitor C_{OUT} with good frequency characteristics and ESR (Equivalent Series Resistance) of which is in the range described as follows:



Measuring Circuit for white noise;R1111N301B

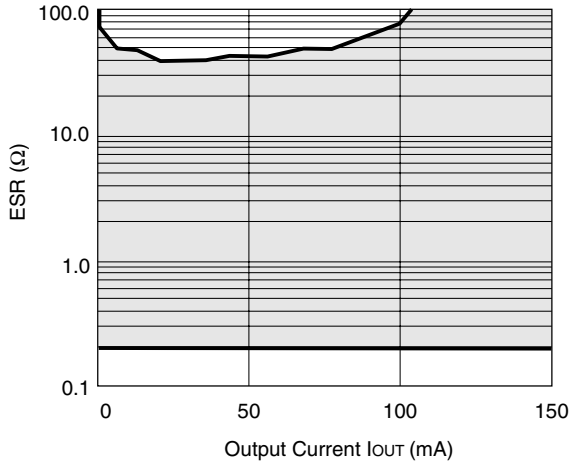
The relationship between I_{OUT} (output current) and ESR of output capacitor is shown in the graphs below. The conditions when the white noise level is under 40µV (Avg.) are indicated by the hatched area in the graph.
(note: When the additional ceramic capacitors are connected to the output pin with output capacitor for phase compensation, the operation might be unstable. Because of this, test these ICs with as the same external components as the ones to be used on the PCB.)

<measuring conditions>

(1) V_{IN}=4V
(2) Frequency band: 10Hz to 1MHz
(3) Temperature: 25°C

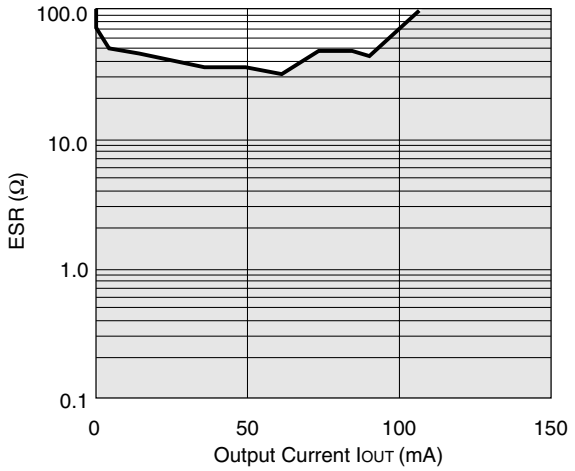
R1111N301B

Ceramic 1.0µF



R1111N301B

Ceramic 2.2µF



- Make V_{DD} and GND lines sufficient. If their impedance is high, noise pick up or incorrect operation may result.
- Connect the capacitor with a capacitance of 1μF or more between V_{DD} and GND as close as possible.
- Set external components, especially the output capacitor, as close as possible to the ICs and make wiring as short as possible.

TYPICAL APPLICATION

